**Experiment: CMOS Inverter Characteristics**

**Aim:**

To implement a Resistive Load inverter and analyze its transient and dc characteristics.

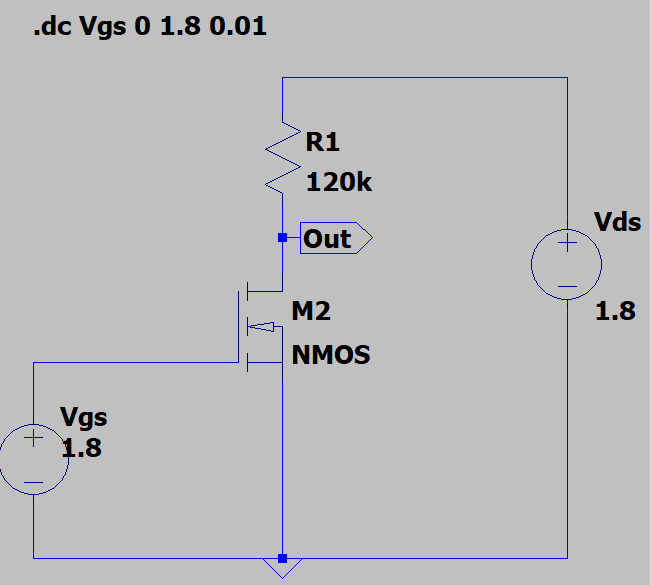
**Tool Used:**

LTspice

**Theory:**

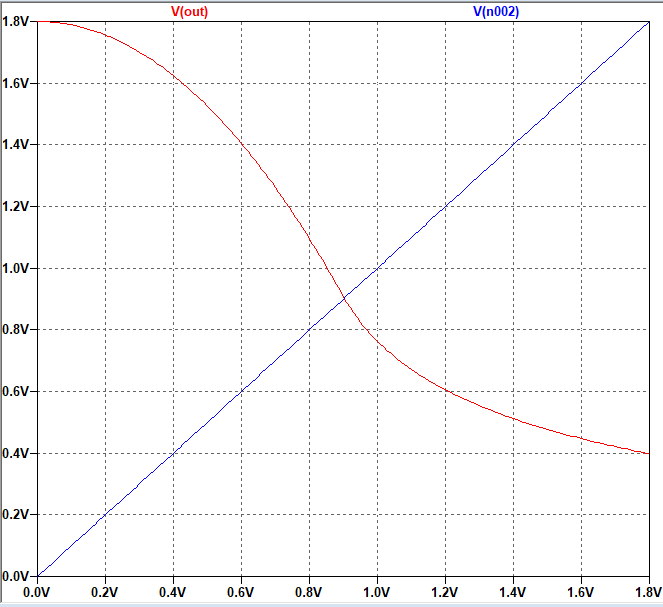
In CMOS technology, both N-type and P-type transistors are used to design logic functions. The same signal which turns ON a transistor of one type is used to turn OFF a transistor of the other type. This characteristic allows the design of logic devices using only simple switches, without the need for a pull-up resistor. In CMOS inverter an n-type MOSFET acts as a pull-down transistor between the output and the low voltage power supply rail (Vss or quite often ground). Instead of the load resistor of Resistive Inverter, CMOS inverter has a p-type MOSFET in a pull-up transistor between the output and the higher-voltage rail (often named Vdd).

**Circuit Schematic:**

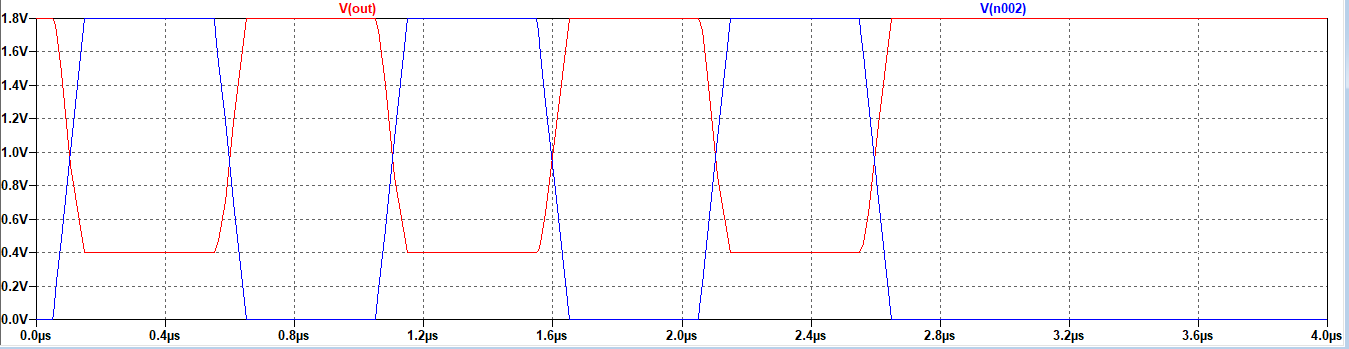
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**Output Waveforms:**

Dc Transfer characteristics (Vgs vs. Vout)



Transient characteristics

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**Result:**

The circuit is stimulated with 120k resistor and the transient and dc characteristics are visualized.